

General Purpose NPN Epitaxial Planar Transistor

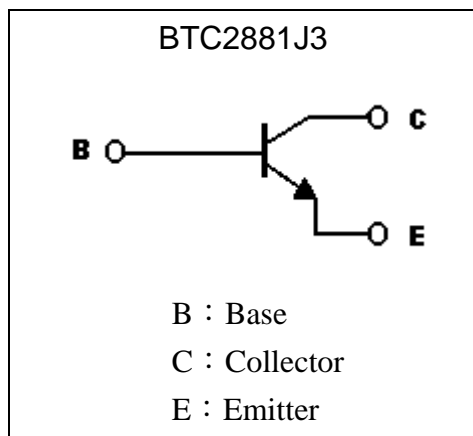
BTC2881J3

BV_{CEO}	200V
I_C	1A

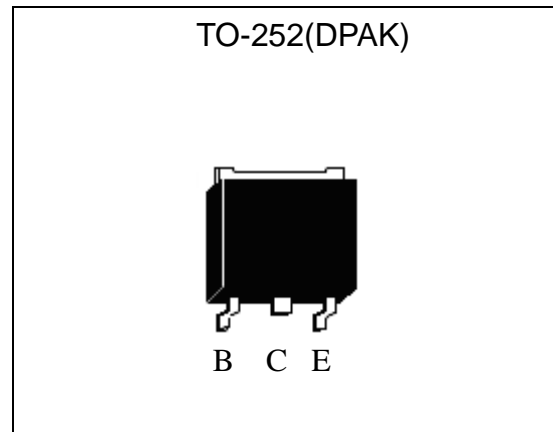
Features

- High breakdown voltage, $BV_{CEO} \geq 200V$
- Large continuous collector current capability
- Low collector saturation voltage
- Pb-free lead plating and halogen-free package

Symbol

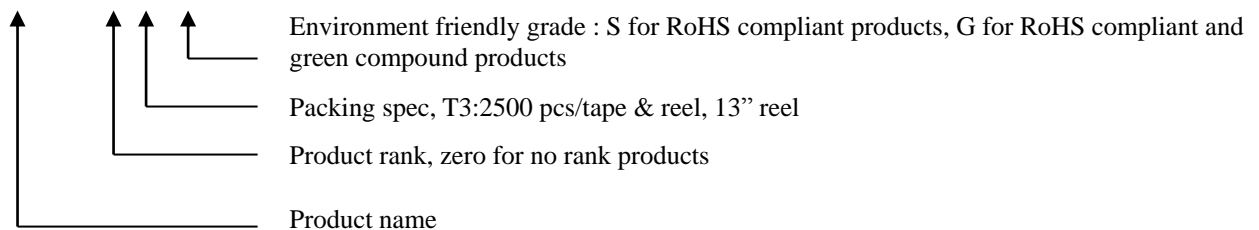


Outline



Ordering Information

Device	Package	Shipping
BTC2881J3-0-T3-G	TO-252 (RoHS compliant package)	2500 pcs / Tape & Reel





Absolute Maximum Ratings (Ta=25°C)

Parameter	Symbol	Limits	Unit
Collector-Base Voltage	V _{CB0}	300	V
Collector-Emitter Voltage	V _{CEO}	200	V
Emitter-Base Voltage	V _{EBO}	6	V
Collector Current	I _C	1	A
Base Current	I _B	0.2	A
Power Dissipation @T _A =25°C	P _D	1	W
Power Dissipation @T _C =25°C		10	W
Operating Junction and Storage Temperature Range	T _j ; T _{stg}	150	°C

Thermal Data

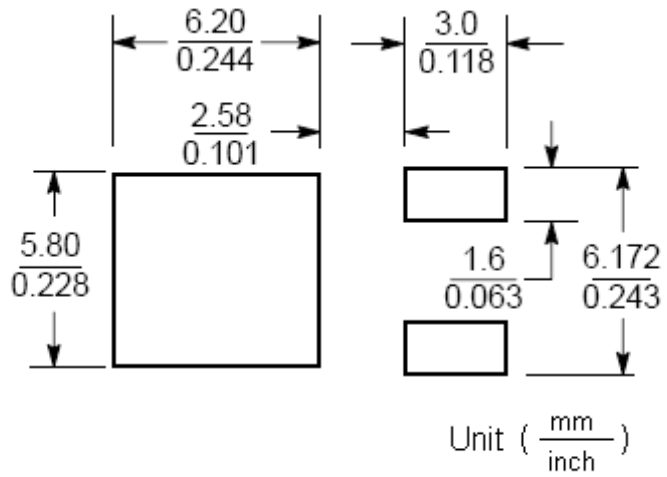
Parameter	Symbol	Value	Unit
Thermal Resistance, Junction-to-case, max	R _{th,j-c}	12.5	°C/W
Thermal Resistance, Junction-to-ambient, max	R _{th,j-a}	125	°C/W

Characteristics (Ta=25°C)

Symbol	Min.	Typ.	Max.	Unit	Test Conditions
BV _{CB0}	300	-	-	V	I _C =10μA
BV _{CEO}	200	-	-	V	I _C =10mA
BV _{EBO}	6	-	-	V	I _E =10μA
I _{CB0}	-	-	100	nA	V _{CB} =300V
I _{EBO}	-	-	100	nA	V _{EB} =6V
*V _{CE(sat)}	-	0.2	0.4	V	I _C =500mA, I _B =50mA
*V _{CE(sat)}	-	-	0.6	V	I _C =700mA, I _B =35mA
*V _{BE(sat)}	-	-	1	V	I _C =500mA, I _B =50mA
*V _{BE(on)}	-	-	1	V	V _{CE} =5V, I _C =500mA
*h _{FE} 1	120	-	-	-	V _{CE} =5V, I _C =50mA
*h _{FE} 2	160	-	320	-	V _{CE} =5V, I _C =100mA
*h _{FE} 3	30	-	-	-	V _{CE} =5V, I _C =700mA
f _T	-	120	-	MHz	V _{CE} =5V, I _C =100mA
C _{ob}	-	-	30	pF	V _{CB} =10V, I _E =0A, f=1MHz

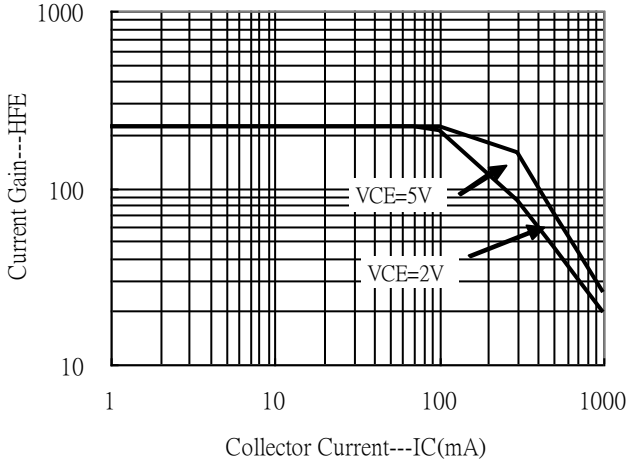
*Pulse Test: Pulse Width ≤300μs, Duty Cycle ≤2%

Recommended soldering footprint

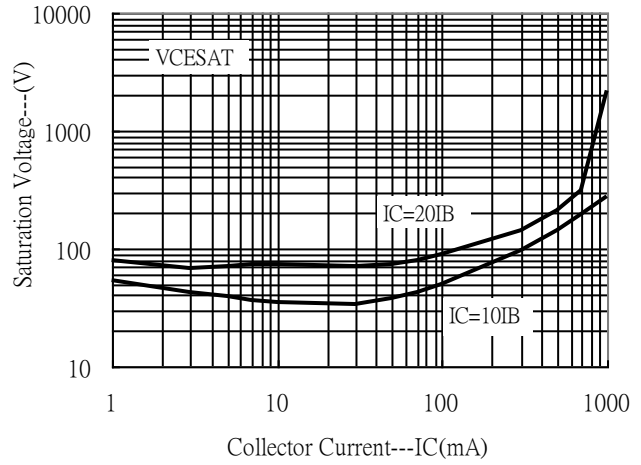


Typical Characteristics

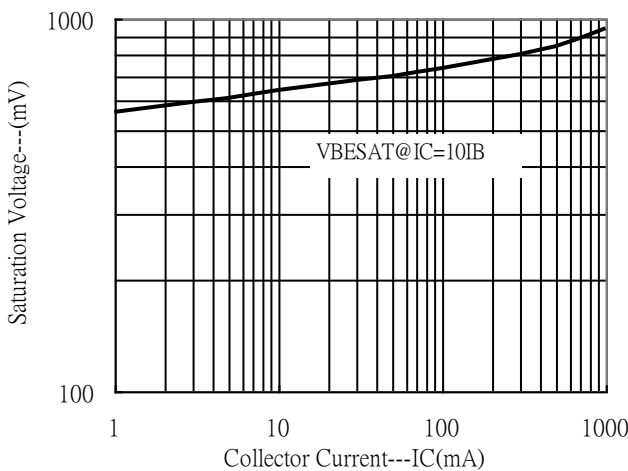
Current Gain vs Collector Current



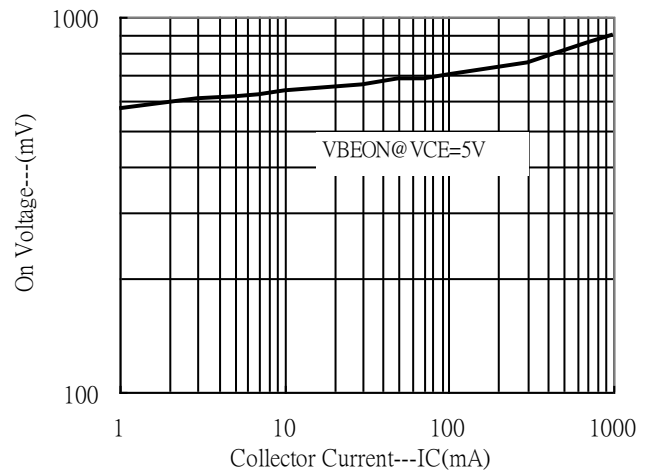
Saturation Voltage vs Collector Current



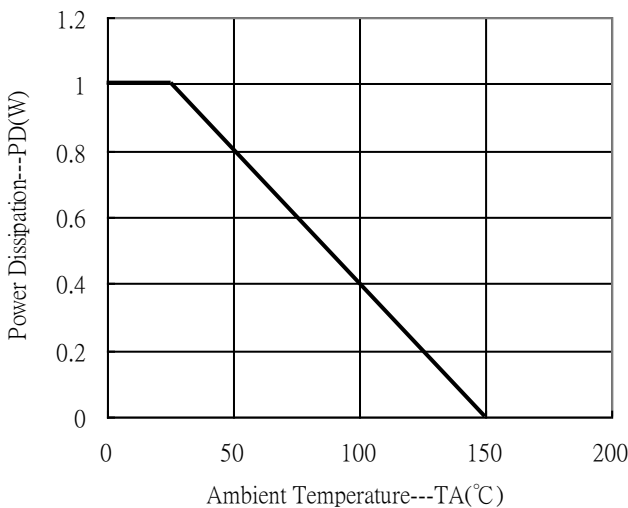
Saturation Voltage vs Collector Current



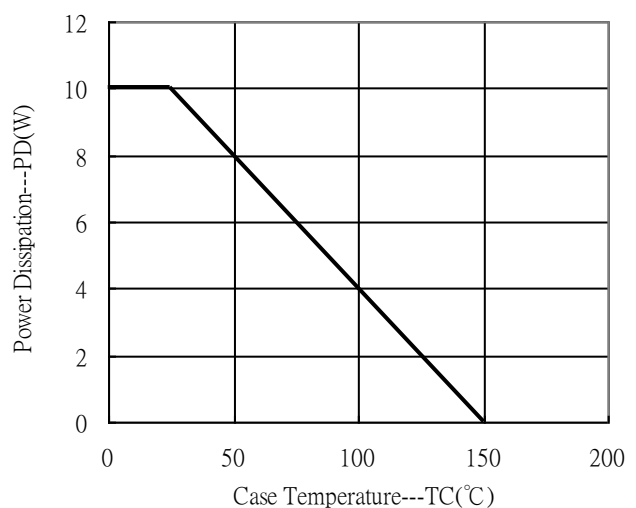
On Voltage vs Collector Current



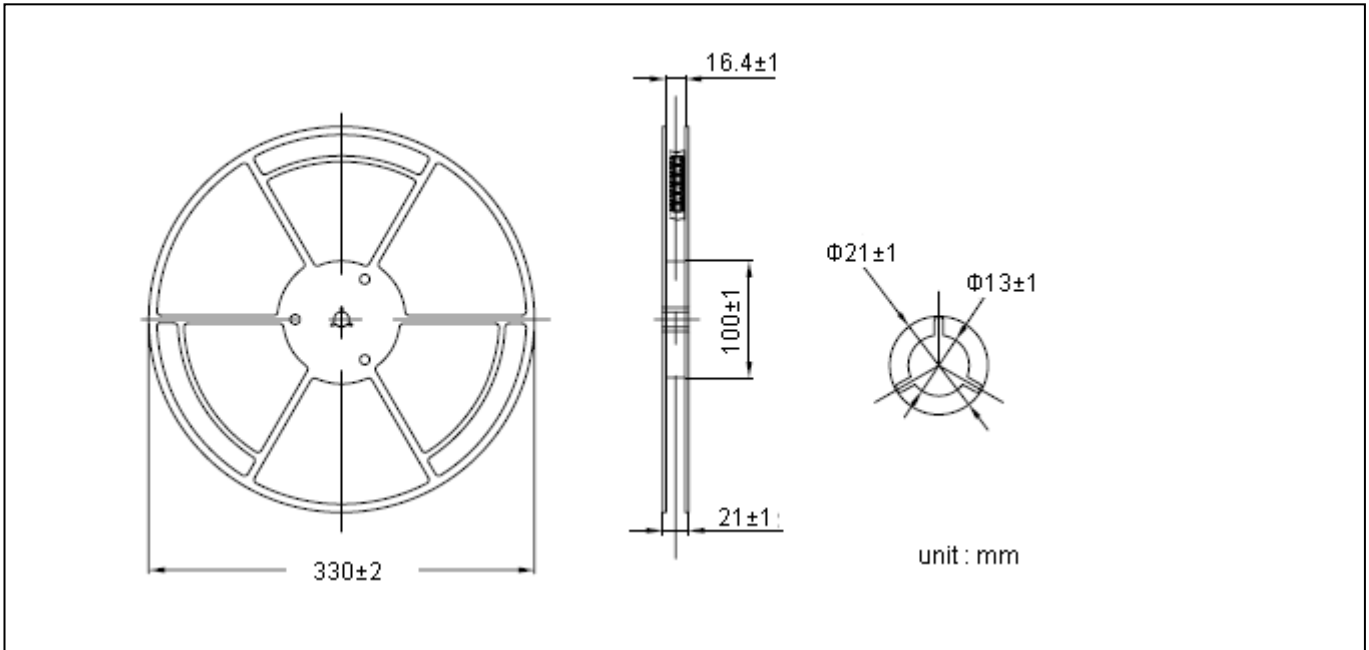
Power Derating Curve



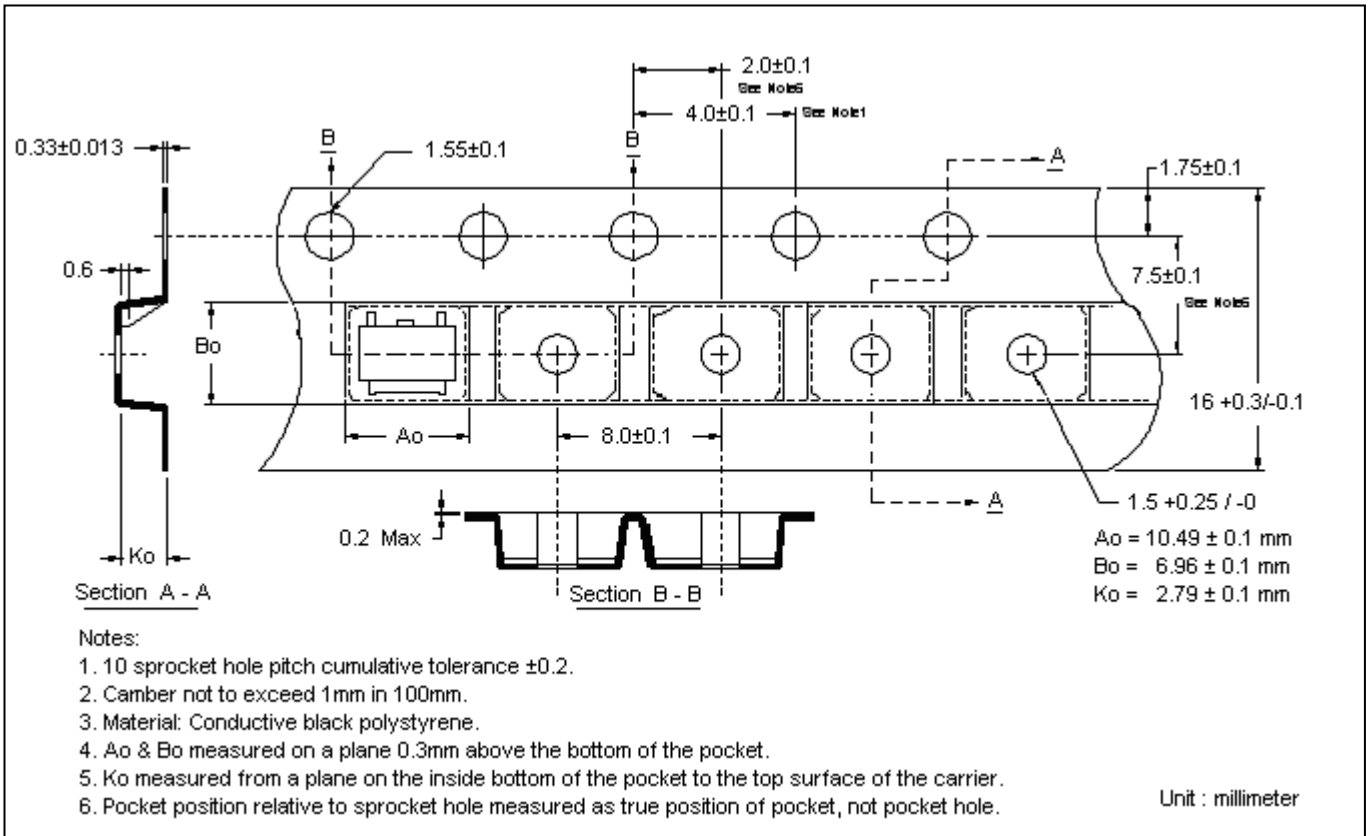
Power Derating Curve



Reel Dimension



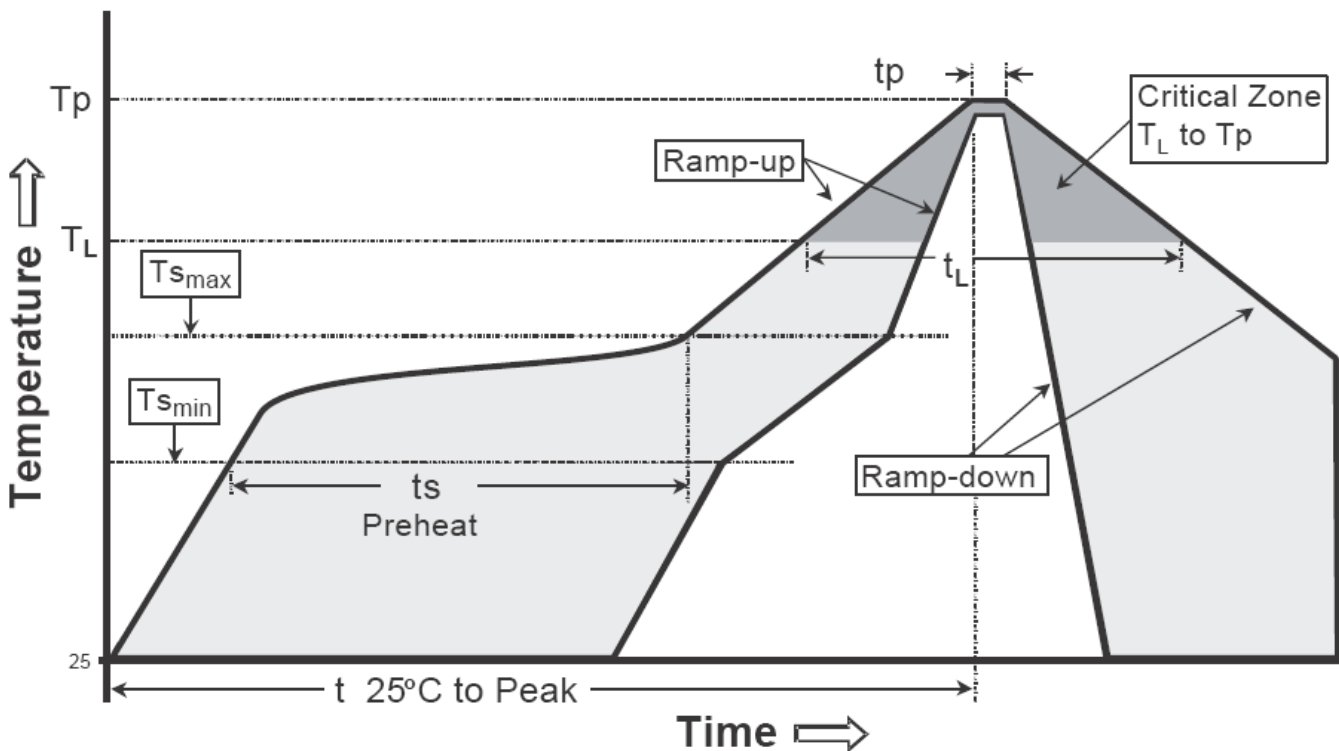
Carrier Tape Dimension



Recommended wave soldering condition

Product	Peak Temperature	Soldering Time
Pb-free devices	260 +0/-5 °C	5 +1/-1 seconds

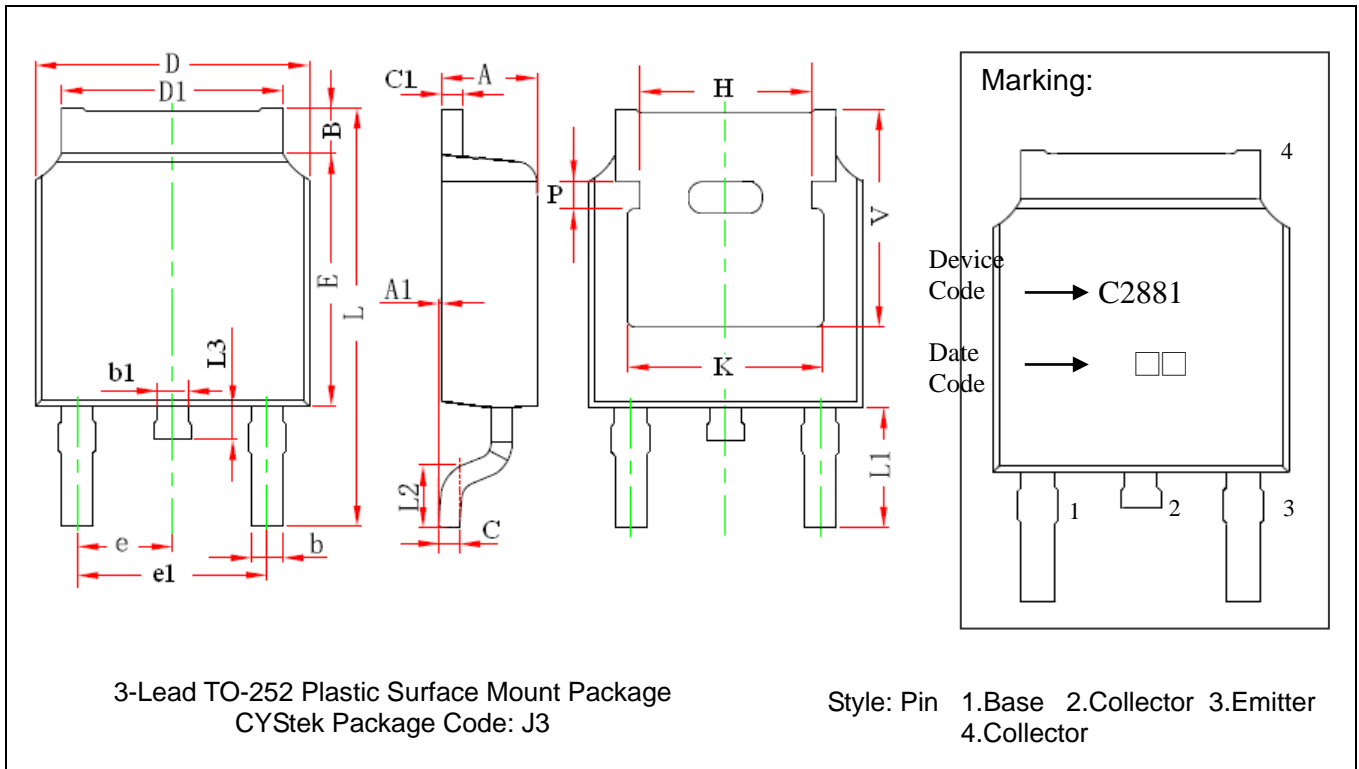
Recommended temperature profile for IR reflow



Profile feature	Sn-Pb eutectic Assembly	Pb-free Assembly
Average ramp-up rate (Tsmax to Tp)	3°C/second max.	3°C/second max.
Preheat		
-Temperature Min(Ts min)	100°C	150°C
-Temperature Max(Ts max)	150°C	200°C
-Time(ts min to ts max)	60-120 seconds	60-180 seconds
Time maintained above:		
-Temperature (Tl)	183°C	217°C
- Time (tL)	60-150 seconds	60-150 seconds
Peak Temperature(Tp)	240 +0/-5 °C	260 +0/-5 °C
Time within 5°C of actual peak temperature(tp)	10-30 seconds	20-40 seconds
Ramp down rate	6°C/second max.	6°C/second max.
Time 25 °C to peak temperature	6 minutes max.	8 minutes max.

Note : All temperatures refer to topside of the package, measured on the package body surface.

TO-252 Dimension



DIM	Inches		Millimeters		DIM	Inches		Millimeters	
	Min.	Max.	Min.	Max.		Min.	Max.	Min.	Max.
A	0.087	0.094	2.200	2.400	e	0.086	0.094	2.186	2.386
A1	0.000	0.005	0.000	0.127	e1	0.172	0.188	4.372	4.772
B	0.039	0.048	0.990	1.210	H	0.163	REF	4.140	REF
b	0.026	0.034	0.660	0.860	K	0.190	REF	4.830	REF
b1	0.026	0.034	0.660	0.860	L	0.386	0.409	9.800	10.400
C	0.018	0.023	0.460	0.580	L1	0.114	REF	2.900	REF
C1	0.018	0.023	0.460	0.580	L2	0.055	0.067	1.400	1.700
D	0.256	0.264	6.500	6.700	L3	0.024	0.039	0.600	1.000
D1	0.201	0.215	5.100	5.460	P	0.026	REF	0.650	REF
E	0.236	0.244	6.000	6.200	V	0.211	REF	5.350	REF

Notes: 1.Controlling dimension: millimeters.
 2.Maximum lead thickness includes lead finish thickness, and minimum lead thickness is the minimum thickness of base material.
 3.If there is any question with packing specification or packing method, please contact your local CYStek sales office.

Material:

- Lead : Pure tin plated.
- Mold Compound: Epoxy resin family, flammability solid burning class: UL94V-0.

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